WATTELH

HTH8G02P550H(B) 550W, 1.8 - 200 MHz LDMOS Amplifier

Product datasheet

Description

The HTH8G02P550H(B) is an unmatched discrete LDMOS Power Amplifier with 550W saturated output power covering frequency range from 1.8 - 200 MHz.

Features

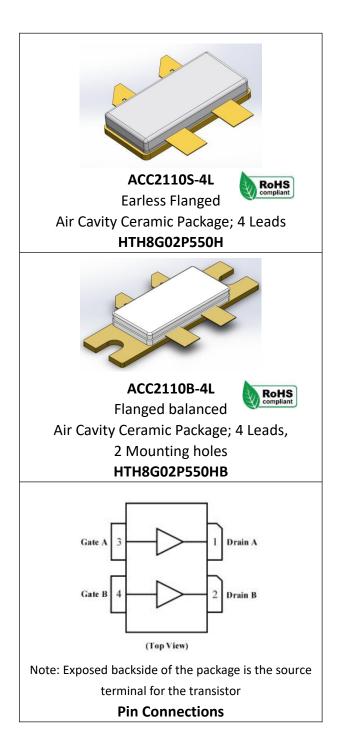
- Operating Frequency Range: 1.8 200 MHz
- Operating Drain Voltage: 28-50V
- Saturation Output Power: 550W
- Internally Unmatched device
- Excellent thermal stability due to low thermal resistance package
- Enhanced robustness design without device degradation
- Internally integrated enhanced ESD design

Applications

- HF VHF band High Power Amplifier
- Broadcasting transmitter
- Industrial Scientific Medical (ISM)
 - Laser generation
 - o Plasma generation
 - o Particle accelerators
 - o MRI, RF ablation and skin treatment
 - Industrial heating, welding and drying systems

Ordering Information

Part Number	Description
HTH8G02P550H(B)	Tray Package
HTH8G02P550H(B)EVB	100 MHz EVB





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Typical Performance

RF Characteristics (CW)

Freq (MHz)	P3dB (dBm)	P3dB (W)	Gain (dB)	Eff(%)@P3dB
100	57.54	558	25.28	70

Test conditions unless otherwise noted: 25 °C, VDD = +50Vdc, IDQ =300mA test on WATECH Application Board

RF Characteristics (Pulsed-CW)

Freq (MHz)	P3dB (dBm)	P3dB (W)	Gain (dB)	Eff(%)@P3dB
100	57.82	580	25.32	75

Test conditions unless otherwise noted: 25 °C, VDD = +50Vdc, IDQ =300mA, PW = 100us, DC= 10% test on WATECH Application Board

Absolute Maximum Ratings

Parameter	Range/Value	Unit
Drain voltage (VDSS)	-0.5 to +135	V
Gate voltage (V _{GS})	-5 to +10	V
Operating Voltage (VDs)	0 to +50	
Storage Temperature (Tstg)	-55 to +150	°C
Junction Temperature (T _J)	-40 to +225	°C

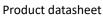
Electrical Specification

DC Characteristics

Parameter	Conditions	Min	Тур	Max	Unit
Breakdown Voltage V(BR)DSS	Vgs=0V, Ids=380uA	-	135	-	V
Gate-Source Threshold Voltage V _{GS(th)}	Vds=10V, Ids=380uA	1.5	2.25	2.9	V
Drain Leakage Current Ibss	Vgs=0V, Vds=50V	-	1	10	uA
Gate Leakage Current Igss	Vgs=5V, Vds=0V	-	0.1	1	uA

Load Mismatch Test

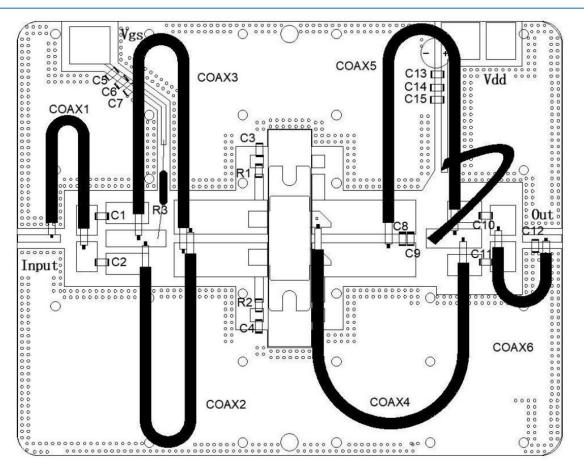
Condition	Test Result
VSWR=65:1 at all Phase Angles, V_{DD} = +50Vdc, I_{DQ} =300mA, Pout = 550W,	No Device
PW = 200us, DC= 20%, freq@100 MHz	Degradation



Thermal Information

Parameter	Condition	Value (Typ)	Unit
Thermal Resistance	TFLANGE= 45°C, V _{DD} = +50Vdc, I _{DQ} =300mA,		
	CW, P _{AVG} = 57.4 dBm (550W),	0.12	°C /W
Junction to Case (RTH)	freq@100 MHz		

HTH8G02P550H(B) 100 MHz Reference Design



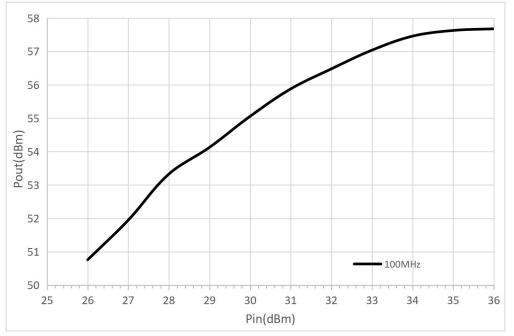
EVB Layout

Bill of Materials (BoM) - HTH8G02P550H(B) 100 MHz Reference Design

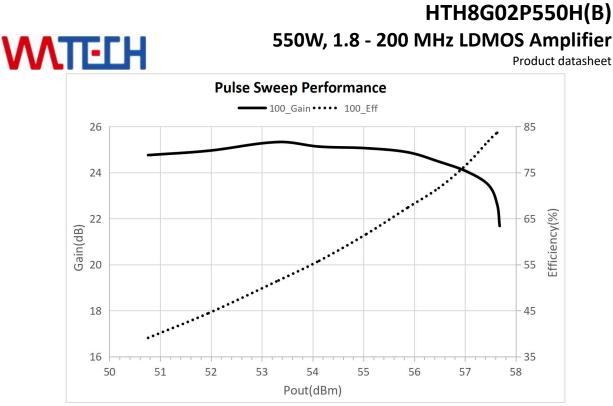
Reference	Value	Description	Manufacturer	P/N
Q1	- 550W, 1.8 - 200 MHz Watech HTH80		HTH8G02P550H(B)	
QI	-	LDMOS PA	watech	11118602755011(B)
C5,C13	4u7F	MLCC	Murata	GRM31CR71H475KA12L
C1,C2,C10,C11	300pF	MLCC	ATC	ATC100B301JT
C8	10pF	MLCC	ATC	ATC100B100JT

WATE	LH	550W, 1.	8 - 200 MHz	LDMOS Amplifier Product datasheet
C9,C12	4p7F	MLCC	ATC	ATC100B4R7JT
C3,C4,C6,C14	1nF	MLCC	Murata	GR321AD72E102KW01D
C7,C15	100pF	MLCC	Murata	GRM1885C1H101JA01
R3	820Ω Wire Resistor		-	-
Coax 2,3	16.7Ω 4:1,110) mm	-	-
Coax 4,5	16.7Ω 4:1, 10	0 mm	-	-
Coax 1	50Ω 2:1,100 r	nm	-	-
Coax 6	50Ω 2:1, 40m	m	-	-
РСВ	RF35 (er = 3.5), 30 mil (0.762 mm), 35 μm (1oz)			

Performance Plots



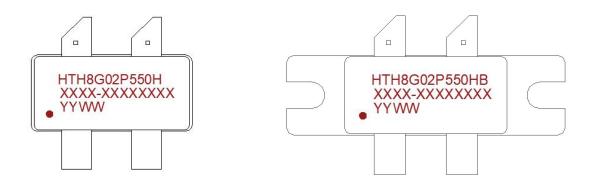
Pulsed CW, Pout vs Pin



Pulsed CW, Gain and Efficiency vs Pout

Test conditions unless otherwise noted: 25 °C, VDD = +50dc, IDQ= 300mA, PW = 100us, DC= 10% test on WATECH Application Board

Package Marking and Dimensions

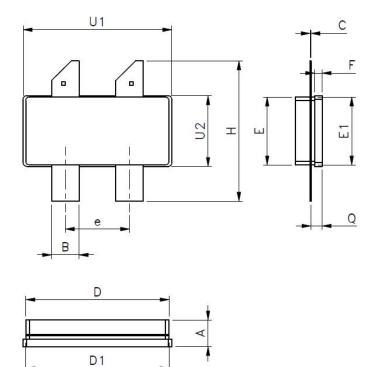


- Line1 (fixed): Device name in W/O
- Line2 (unfixed): Marking Lot No in W/O (Sample: E596-EERA0001)
- Line3 (unfixed): Date Code

This Marking SPEC only stipulates the content of Marking. For marking requirements such as font and size, please refer to the latest version of "Watech Product Printing Specification"

Marking

Product datasheet



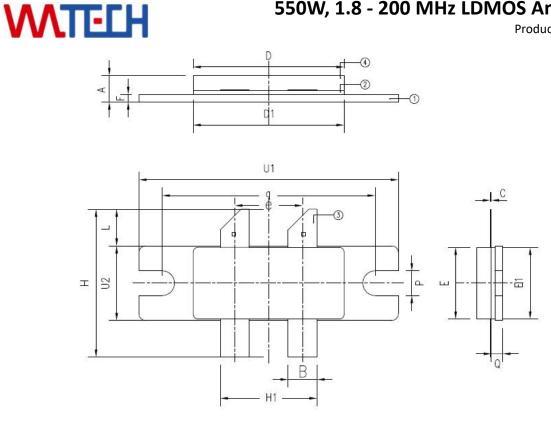
Gumbal	Dimesions in Milimeters			[Dimesions in Inche	s
Symbol	Min.	Mon.	Max.	Min.	Mon.	Max.
А	3.12	3.69	4.26	0.123	0.145	0.168
В	3.69	3.81	3.93	0.145	0.150	0.155
С	-	0.11	-	-	0.004	-
D	19.61	19.81	20.01	0.772	0.780	0.788
D1	19.66	19.81	19.96	0.774	0.780	0.786
E	9.273	9.4	9.527	0.365	0.370	0.375
E1	9.28	9.4	9.52	0.365	0.370	0.375
F	0.95	1.02	1.09	0.037	0.040	0.043
н	19.38	19.43	19.48	0.763	0.765	0.767
Q	1.46	1.53	1.6	0.057	0.060	0.063
U1	20.51	20.58	20.65	0.807	0.810	0.813
U2	9.71	9.78	9.85	0.382	0.385	0.388
е	8.77	8.89	9.01	0.345	0.350	0.355

Package Dimensions

ACC2110S-4L Earless Flanged Ceramic Package; 4 leads

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Gumbal	Dimesions in Milimeters			[Dimesions in Inche	s
Symbol	Min.	Mon.	Max.	Min.	Mon.	Max.
А	3.55	3.71	3.86	0.140	0.146	0.152
В	3.68	3.81	3.94	0.145	0.150	0.155
С	0.04	0.11	0.18	0.002	0.004	0.007
D	19.61	19.81	20.01	0.772	0.780	0.788
D1	19.61	19.81	20.01	0.772	0.780	0.788
E	9.28	9.40	9.52	0.365	0.370	0.375
E1	9.28	9.40	9.52	0.365	0.370	0.375
F	0.95	1.02	1.09	0.037	0.040	0.043
Н	18.93	19.43	19.93	0.745	0.765	0.785
H1	12.57	12.70	12.83	0.495	0.500	0.505
L	4.71	4.83	4.95	0.185	0.190	0.195
Р	3.12	3.25	3.38	0.123	0.128	0.133
Q	1.43	1.53	1.63	0.056	0.060	0.064
q	-	27.94	-	-	1.10	-
U1	33.91	34.04	34.16	1.335	1.340	1.345
U2	9.71	9.78	9.85	0.382	0.385	0.388
е	-	8.89	-	-	0.35	-

Package Dimensions

ACC2110B-4L Flanged Ceramic Package; 2 mounting holes; 4 leads

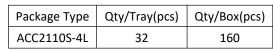
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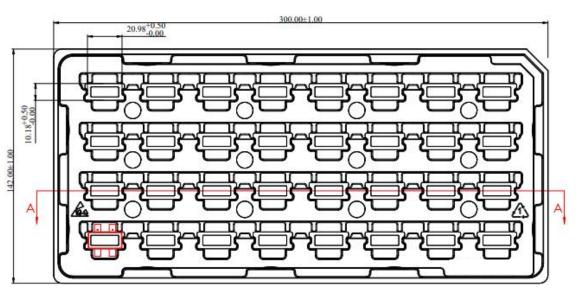
HTH8G02P550H(B) 550W, 1.8 - 200 MHz LDMOS Amplifier

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Packing Information

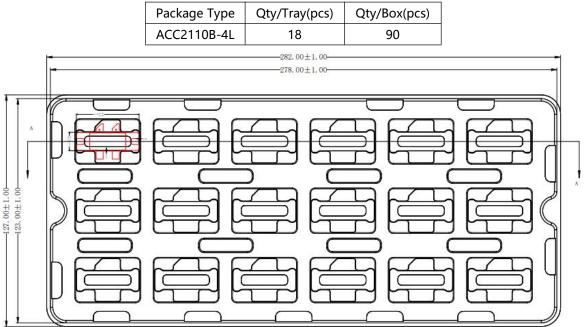
HTH8G02P550H:





HTH8G02P550H Packaging Descriptions





HTH8G02P550HB Packaging Descriptions

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HTH8G02P550H(B) 550W, 1.8 - 200 MHz LDMOS Amplifier

Product datasheet

Handling Precautions

Parameter	Grade
Moisture Sensitivity Level MSL	3

Parameter	Rating	Standard	
ESD – Human Body Model (HBM)	Class 1B	JESD22-A114	ATTENTION OBSERVE PRECAUTIONS
ESD – Human Body Model (MM)	Class A	EIA/JESD22-A115	FOR HANDLING ELECTROSTATIC SENSTIVE DEVICES
ESD-Charged Device Model (CDM)	Class III	JESD22-C101	

RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

Datasheet Status

Document status	Product status	Definition	
Objective Datasheet	Design simulation	Product objective specification	
Preliminary Datasheet Customer sample		Engineering samples and first test results	
Product Datasheet Mass production		Final product specification	

Abbreviations

Acronym	Definition
LDMOS	Laterally-Diffused Metal-Oxide Semiconductor
CW	Continuous Waveform

Revision history

Document ID	Datasheet Status	Release Date	Revision Version
Rev 1.0	Preliminary	Dec. 2021	Preliminary
Rev 1.1	Objective	March 2023	New format based on English version datasheet
Rev 2.0	Product	Sept.2023	Update TBD information
Rev 2.1	Product	Aug.2024	Update package information

Contact Information

HTH8G02P550H(B) 550W, 1.8 - 200 MHz LDMOS Amplifier

Product datasheet

For the latest specifications, additional product information, worldwide sales and distribution locations and information about WATECH:

- Web: <u>www.watechelectronics.com</u>
- Email: <u>MKT@huatai-elec.com</u>

For technical questions and application information:

• Email: <u>MKT@huatai-elec.com</u>

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